BALAYEVA, I.A. (Moskva); CHEPRASOV, V.A. (Moskva)

Method for determining initial deviations of a gyrocompass. Isv. AN SSSR Otd. tekh. nauk. Mekh. i mashinostr. no.2:136-137 Mr-Ap <sup>1</sup>63. (MIRA 16:6)

(Gyrocompass)

#### CHEPRASOV, V.P.

[Galculation of potential flow around isolated profiles and hydrodynamic cascades] Raschet potentsial nogo obteknnia isolirovannykh profilei i gidrodinamicheskikh reshetok; avtoreferat dissertatsii, predstavlennoi na soiskanie uchenoi steponi kandidata tekhnicheskikh nauk. Nauchayi rukovoditel! G.G.Tunashev. Kazan\*, Kazanskii aviatsionnyi institut, 1955. 9 p.

(Aerodynamics) (MIRA 9:3)

CHEPRASOV, V.P.

Flotting flow off profiles and cascades of arbitrary shape. Isv.
vys. ucheb. sav.; av. tekh. no.2:121-127 '58. (MIRA 11:6)

1. Kasanskiy aviatsionnyy institut, Kafedra aerodinamiki.
(Fluid dynamics)

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3/124/60/000/004/007/027 A005/A001

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Translation from: Referativnyy zhurnal, Mekhanika, 1960, No. 4, pp. 42-43, # 4491

AUTHOR:

والإستارة

Cheprasov, V.P.

TITLE:

Calculation of the Potential Flow Around Isolated Profiles and

Hydrodynamical Cascades |

PERIODICAL:

Tr. Kazansk. aviats. in-ta, 1958, Vol. 38, pp. 43-56

A calculation procedure is expounded, dealing with the potential TEXT: flow around a single wing profile and similar to the known Theodorsen-Serebriyskiy method. Mapping the exterior of the prescribed profile onto the contour exterior, approximating the circle, is performed by a mapping function determining the conformal map of the theoretical profile exterior, similar to the described, onto the circle exterior. Mapping this contour onto the unit circle exterior with an accuracy up to minute quantities of second order is performed by the M.A. Lavrent' yev function or its certain generalization. The author recommends to use, for plotting the theoretical profile, the S.A. Chaplygin mapping function. An analogous solution is obtained for the cascade of arbitrary profiles. Assuming that the function is known, which states the conformal correspondence between the points

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Calculation of the Potential Flow Around Isolated Profiles and Hydrodynamical Cascades

of regions outside the cascade of the unit radius circles and outside the cascade of the theoretical profiles, whereat the latter cascade is similar to the prescribed cascade, the author used this function to mapping the exterior of the prescribed cascade onto the cascade exterior of the contours similar to the circles. In this way, the problem is reduced to determining an analytic function, which maps the cascade exterior of the contours similar to the circles onto the circle cascade exterior. The latter function is found in the form:

$$\xi_1 = \zeta + \sum_{n=0}^{\infty} c_n \left[ F_1(\zeta) \right]^n$$

where  $\zeta_1 = r_1 e^{i\theta_1}$  is the circle cascade plane,  $\zeta_1 = r_1 e^{i\theta_1}$  is the cascade plane of the contours similar to the circles,

$$F_1(\zeta) = R(r,\theta)e^{i\vartheta(r,\theta)}$$

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Calculation of the Potential Flow Around Isolated Profiles and Hydrodynamical Cascades

is a function introduced by E.L. Blokh as the periodical part of the complex potential of the circulationless flow around the circle cascade. The coefficients  $C_n = A_n + iB_n$  can be found by solving the algebraic equation system obtained from the relation

 $\xi_{1}(\xi)\overline{\xi_{1}(\xi)} = r_{1}^{2}$ 

when the contour equations are presented in the  $\xi$  plane in the forms  $\xi = [1 + \Delta r (\vartheta)] e^{i\vartheta} + ikt (k = 0, \pm 1, \pm 2, ..., \infty),$ 

 $\mathcal{G} = \begin{bmatrix} 1 + \Delta \mathbf{r} & (\mathcal{F}) \end{bmatrix} e^1 + ikt \quad (k = 0, \pm 1, \pm 2, ..., \infty),$ and the  $\Delta \mathbf{r} & (\mathcal{F})$  function as a Fourier series. Then, the coefficients  $A_n$ ,  $B_n$  can be expressed by the Fourier series coefficients. The method of successive

can be expressed by the Fourier series coefficients. The method of successive approximations for determining the coefficients  $A_n$ ,  $B_n$  is expounded, whereat the convergence rate of the successive approximation procedure depends on the degree of similarity of the theoretical profile cascade to the prescribed profile cascade. The plotting of theoretical profile cascades is carried cut using a mapping function representing a generalization of the Chaplygin function for the case of

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Calculation of the Potential Flow Around Isolated Profiles and Hydrodynamical Cascades

a profile cascade by means of the E.L. Blokh function  $F_1$  ( $\zeta$ ), so that the function obtained yields a conformal mapping of the circle cascade exterior onto the exterior of the theoretical profile cascade of the same step. The formulae for calculating the velocities along the profile cascade contour are given and the comparison of the computational and experimental velocity distribution along the profile contour of a dense cascade is carried out, which consists of thick strongly buckled profiles.



A.S. Ginevskiy

Translator's note: This is the full translation of the original Russian abstract.

Card 4/4

SOV/124-59-10-11561

Translation from: Referativnyy zhurnal, Mekhanika, 1959, No. 10, p. 74 (USSR)

AUTHOR: Cheprasov, V. P.

TITLE: Equations of Curvilinear Motion of an Elastic Blade

PERIODICAL: Tr. Kazansk. aviats. in-ta, 1958, Vol. 43, pp. 87-102

TEXT: The system of five differential equations is established for calculating the rotor blade motion, when a stroke governor, horizontal and vertical hinges, and a skew-control automat exist. It is assumed that the angular velocity of the propeller blade turn amounts to less than 0.1 of the angular velocity of revolution; the calculation of the aerodynamic loads is based on the hypothesis of steadiness; the induced velocity is given as a trigonometric series.

G. I. Maykapar

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S/044/60/000/007/013/058 C111/C222

16.3000

Cheprasov, V.P.

AUTHOR:

Calculation of the potential flow around of isolated

profiles and hydrodynamic grids

PERIODICAL: Referativny shurnal. Matematika, no.7, 1960, 79-80.

Abstract no.7546. Tr. Kazansk. aviats. in-ta, 1958, 38, 43-56

TEXT: The author considers the calculation of the potential flow around of isolated profiles and of grid profiles of an arbitrary form by an incomp-ressible fluid. The author's method for the calculation of the potential flow around of an isolated profile is a certain modification of the well-known method of Theodorsen-Serebriyskiy. The nature of the author's method consists in the following:

We assume that it is possible with the aid of the known function to

We assume that it is possible with the aid of the known function to construct a theoretical profile c which is little different - according to the position and the curvature - from the given profile c so that

 $|\delta(s)| < \epsilon$ ,  $|\delta'(s)| < \epsilon$ ,  $|\delta''(s)| < \epsilon$  (1)

is satisfied with a possible exception of a finite number of points. Here  $\delta(s)$  is the length of the piece of the normal of the profile c Card 1/5

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Calculation of the potential flow...

between c and c. Let D(c) be the external region with respect to the given profile, while D(c) is the external region with respect to the theoretical profile c; let  $\omega = f(z,c)$  be the function which maps conformally the region D(c) onto the exterior of the unit circle c:  $|\omega| \ge 1$ . For this mapping, to the profile c in the  $\omega$ -plane there corresponds the curve c which is little different from the circle c:  $|\omega| = 1$ . The author uses the approximation formulas for conformal mappings of little different regions, namely the approximation formulas of M.A.Lavrent'yev, for the conformal mapping of the exterior of regions being little different from the circle onto the exterior of the unit circle. He gives an approximate construction of a function S = f(z,c),  $f(\omega,c) = \omega$ ,  $f'(\omega,c) > 0$  which maps conformally the exterior of the given profile c, i.e. of the region D(c) being little different from the region D(c), onto the exterior of the unit circle c: |S| = 1 of the plane  $S = \frac{1}{2} + i\eta$ . Using the equation of the curve C in the form

$$\widetilde{\omega}_{\widetilde{c}^*} = [1 + \delta^*()] e^{i\theta_1}$$

then for the mentioned mapping Card 2/5

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Calculation of the potential flow...

$$\int_{0}^{2\pi} \int_{0}^{2\pi} \int_{0}^{2\pi$$

$$f(\infty, \hat{\sigma}) = \infty$$
,  $f'(\infty, \hat{\sigma}) > 0$ .

The correspondence of the points of the regions  $D(\widetilde{c})$  and  $D(\widetilde{c}^{\sharp})$  is fixed by the inversion of S.A.Chaplygin's function

$$z = \frac{(\omega - 1)^2}{\omega + \varepsilon_0}, \qquad (2)$$

where  $\mathcal{E}_0 = \zeta_0 + i \eta_0$  — the parameters of the calculation are chosen so that the theoretical profile constructed with the aid of (2) is little different from c in the sense of (1). Here the Fourier series of the function  $\delta^{\#}(\theta_1)$ 



$$\delta^{*}(\theta_{1}) = \sum_{n=0}^{\infty} (a_{n} \cos n\theta_{1} + b_{n} \sin n\theta_{1}), \qquad (3)$$

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Calculation of the potential flow...

 $a_n = b_n = o(\frac{1}{n^2})$  will be absolutely and uniformly convergent. The

author uses the development (3) and finds the approximation expression of the sought mapping function in the form

 $\zeta = (1-c_0)\omega - \sum_{n=1}^{\infty} \frac{c_{-n}}{\omega^{n-1}},$  (4)

where  $c_n = a_n + ib_n$ , and the series (4) is absolutely convergent in the region  $|\omega| \ge 1$ .

Furthermore the author uses the well-known method of the expansion in terms of powers of the small parameter (L.V.Kantorovich and V.I.Krylov, Approximation Methods of Higher Analysis, M., 1952) and seeks a more general function which maps the region  $D(\widehat{c})$  onto  $D(c^{\frac{1}{2}})$  in the following form

 $\zeta = \omega + \sum_{k=1}^{\infty} \varepsilon^{k} P_{k}(\omega), \tag{5}$ 

 $\zeta(\infty) = \infty, \left| \frac{d\zeta}{d\omega} \right|_{\infty} > 0,$ 

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Calculation of the potential flow...

where £ is a fixed positive magnitude, Pk(a) at first are unknown

functions being holomorphic outside the curve  $\tilde{c}$  and having a single pole  $\omega = \infty$  in the neighborhood of which they are representable in the form

$$P_k(\omega) = \sum_{v=-1}^{\infty} \frac{d_{-v,k}}{\omega^k}.$$

A method for the successive determination of the necessary number of functions  $P(\omega)$  of the sequence  $\{P_k(\omega)\}$  is given. After the determination of the mapping function  $f=f(z,\tilde{c})$  the velocity field in the flow plane is calculated with usual methods. Examples are given. The problem of the flow around of an arbitrary profile grid is solved with an analogous method; here the author uses the functions introduced by E.L. Blokh and Ye.I.Umnov.

Abstracter's note: The above text is a full translation of the original Soviet abstract.

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ACCESSION NR: ARAO14683

8/0271/64/000/001/A031/A031

SOURCE: RZh. Avtomatika, telemakhanika i vy\*chislitel'maya tekhnika, 1964, mo. 1, Abs. 1A205

AUTHOR: Cheprasov, V. P.

TITLE: One problem in the synthesis of optimal control with restrictions on the phase coordinates and on the rate of change in the controlling action

CITED SOURCE: Tr. Kasansk. aviats. in-ta, vy\*p. 75, 1963, 91-101

TOPIC TAGE: transient process, control system, exponential stability, control trajectory, restricted control, optimal control, dynamic programming, control system synthesis

TRANSLATION: The analytical structure is examined of regulators for systems whose transient processes have a prescribed exponential stability. The control law is sought which provides the exponential stability, smoothness of trajectories, and yields the minimum value of the functional

1(ξ) = <sup>6</sup>/<sub>2</sub>(x,ξ,ξ)dt,

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#### ACCESSION NR: AR4014683

where x is the n-dimensional vector of the phase state of the system, and £ is the r-dimensional vector of the control force. It is proved that control £ (s,t) can be constructed by using the two Lyapunov functions VO (s, t) and g(s,t). Here z is a positive-definite quadratic form of x and £. The Lyapunov functions must satisfy certain conditions which are necessary and sufficient for optimal control in the sense that functional I( £) is minimum, and sufficient for exponential stability and smoothness of trajectory. Proof is given for the sufficiency and necessity of these conditions. Mecessity is proved by the method of dynamic programming. An example is given of determining control in a second order system having a restricted rate of change in the controlling action. Orig. art, has 12 refs.

SUB CODE: CE

ENCL: 00 DATE ACQ: 19Feb6L

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5-2

USSR/Human and Animal Morphology (Normal and Pathological). Nervous System. Peripheral Nervous System.

Abs Jour: Ref Zhur-Biol., No 16, 1958, 74308

Author: Cheprasova, A. F.

Inst: Stalinabad Medical Institute.

Title: On the Question of Duodenal Innervation

in a Dog (Experimental-Morphologic Study).

Tr. Stalinabadsk. med. in-ta, 1957, 25, Orig Pub:

191-197

Four series of experiments were conducted Abstract:

on dogs; in the 1st, resection of the sto-mach according to Billroth I was performed; in the 2nd, the right, and in the 3rd, the left semilunar ganglion of the solar plexus

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USSR/Human and Amimal Morphology (Normal and S-2 Pathological). Nervous System. Peripheral Nervous System.

Abs Jour: Ref Zhur-Biol., No 16, 1958, 74308

was removed, and in the 4th, subdiaphragmal vagatory was performed. It was determined that the source of duodenal innervation is the left and right semilunar ganglia of the solar plexus, and that in the composition of the fibers which innervate the duodenum there are medullated and nonmedullated nerve fibers. The participation of fibers of the vagal nerve in the innervation of the duodenum was confirmed. — D. D. Ivanov

Card : 2/2

# CONSTANTINESCU, N.,; DUCA, M.,; DUCA, B.,; CHEPTRA, A.

Experimental paralytic rabies cured or autosterilized in partially immunized animals. Stud. cercet. inframicrobiol., Bucur. 6 no.1-2:9-16 Jan-June 55.

1. Institut de Inframicrobiologie al Academiei R.P.R. si Institutul de medicina din Iasi.

(RABIES, experimental

in rate partially immunized with Fermi vacc., recovery & autosterilization)

(VACCINES AND VACCINATION

rabies vacc., Fermi vaccine in exper. rabies)

COMSTANTINESCU, N.; STIRBU, A.; CHIPTEA, A.; TAINDEL, C.

Effect of the schedule of therapy in anti-rables vaccination before and after infection. Stud. cercet. inframicrobiol.,
Bucur. 6 no.3-4:375-387 July-Dec 1955.

(RABIES, prevention & control
vacc. with Fermi vaccine, prev. & ther. results in exper. animals, eff. of timing & dos. of vaccine before & after infect. with street virus)

(VACCINES AND VACCINATION rabies, Fermi vaccine, prev. & ther. results in exper. animals, eff. of timing & dos. of vaccine before & after infect. with street virus)

CHEFTEHIN

CONSTANTINESCU, N.; STIRBU, A.; CHEPTEA. A. TAINDEL, C.

Study of the comparative protective action of rables antiserum and phenolated vaccines in experimental rables. Stud. cercet. inframicrobiol., Bucur. 7 no.3-4:423-470 July-Dec 56.

1. Comunicare presentata in medinta Institutului de inframicrobiologie al Academiei R.P.R.

(RABIES, experimental

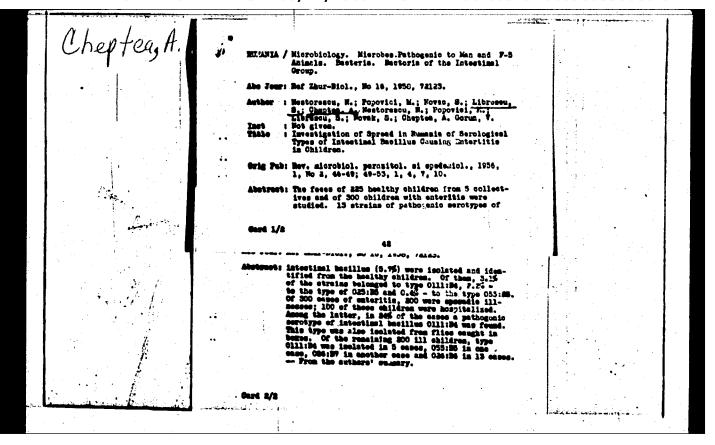
comparative eff. of rabies antiserum & phenolated vaccines)

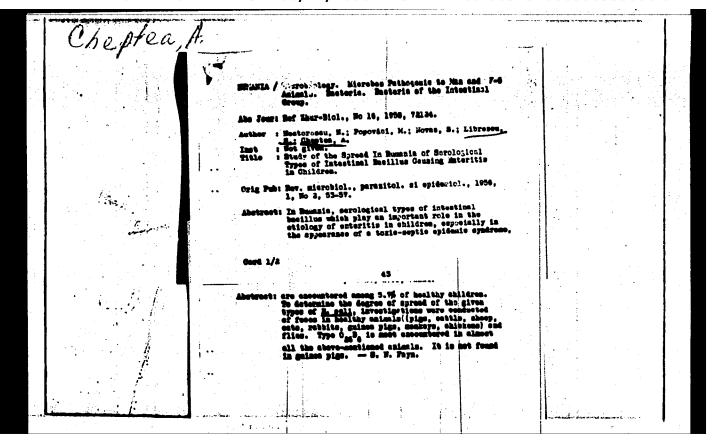
(IMMURE SERUMS

rabies antiserum, protective eff. in exper. rabies, comparison with phenolated vaccines)

(VACCINES AND VACCINATION

rabies phenolated vaccine, protective eff. in exper. rabies. comparison with antiserum)





VOYE, A.A., insh.; SEREBRYAKOV, A.M., insh.; CHEPTSOV, V.V., insh. (Irkutsk).

Mechanized elag removal. Put' i put. khoz. no.1:29-30 Ja 158.

(Slag) (Conveying machinery) (MIRA 1.:1)

SHPUNTOVA, M.Ye.; SHNAYDER, Ye.Ye.; CHEPUGO, S.V.; LAZAREVA, L.V.;
MASLOVA, L.G.; ROSHCHINA, V.I.; Prinimali uchastiye: PAVLENKO, V.M.,
starshiy laborant; GERASIMOVA, L.I., starshiy laborant

Pentose hydrolysis of cottonseed hulls and corncobs with hexose hydrolyzates. Sbor.trud. NIIGS 11:7-15 '63. (MIRA 16:12)

CHEPUKHALIN Inzh.

Ways of eliminating nonproductive idle time of ships in ports. Mor. flot 19 no.7:6-9 J1 '59.

(MIRA 12:10)

1.Slushba portov i morskikh putey Kaspiyskogo parokhodstva. (Harbors) (Loading and unloading)

# CHEPUKHALIN, I., inzh.

Practical problems in standardizing the loading and unloading of ships in sea harbors. Mor.flot 20 no.10:7-9 0'60. (HIRA 13:10)

1. Sluzhba portov i morskikh putey Kaspiyskogo parokhodstva. (Gargo handling-Standards)

#### CHIPURHALIN, I., insh.

Increase the responsibility for freight carried in mixed communications. Nor. flot 20 no. 12:4-5 D '60. (MIRA 13:12)

1. Sluzhba portov i morskikh putey Kaspiyskogo parokhodstva. (Freight and freightage)

## CHEPUKHALIN, I., aspirant

Ways to improve the methods of calculating labor productivity indices for loading and unloading operations in sea harbors.

Mor.flot 22 no.1:6-9 Ja \*62. (MIRA 15:1)

1. Institut kompleksnykh transportnykh problem.
(Cargo handling--Labor productivity)
(Longshoremen)

ZININ, V.; PAPER, A.; CHEPUKHALIN, I., aspirant

The planning of sea harbor operations should meet modern objectives. Mor. flot 23 no.9:14-16 S \*63. (MIRA 16:11)

1. Nachal'nik otdela truda i sarabotnoy platy Kaspiyakogo parokhodstva (for Zinin). 2. Nachal'nik planovogo otdela Bakinskogo porta (for Paper). 3. Institut komplekanykh transportnykh problem (for Chepukhalin).

# CHEPUKHALIN, I., aspirant

Regulate volume measurements in the loading and unloading of cargo in harbors. Mor. flot 23 no. 12:12-14 D '63. (MIRA 17:5)

1. Institut kompleksnykh transportnykh problem.

CHEPULIS, I.I.

"Reserve Alkalinity, Carbon Anhydrase, and Blood Gases During Experimental Pneumonia." Cand Vet Sci, Leningrad Veterinary Inst, Leningrad, 1954. (RZhBiolKhim, No 7, Apr 55)

SO: Sum. No. 704, 2 Nov 55 - Survey of Scientific and Technical Dissertations Defended at USSR Higher Educational Institutions (16).

CHEPULIS, I.P., Cand Agr Sci-(diss) "Growth, development, productivity, and certain biological productivities of ordesbood and purebred but under conditions of Lithanian SSR." Lon, 1958. 22 pp (Lin of Agr USSR.

Lon Vet Inst. Chair of Animal Husbandry), 100 copies (KL, 26-58, 114)

-117

GABRIOLAVICHUS, V.I. [Gabriolavicius, V.]; CHEPULIS, I.I. [Cepulis, F.]

Percussion of the ventral part of the abdominal wall in traumatic reticuloperitonitis. Veterinariia 39 no.1:49-51 Ja '63.

(MIRA 16:6)

(Peritonitis) (Percussion) (Lithuania--Cattle--Diseases and pests)

YANONIS, B.P. [Janonis, B.], dotsent; CHEPULIS, I.I. [Cepulis, I.], dotsent; BAKUNAS, I.I., ordinator

Rumenography in traumatic reticulitis of cattle. Veterinariia 40 no.9: 53-55 S '63. (MIRA 17:1)

1. Litovskaya veterinarnaya akademiya.

Name: CHEPULIS, Stanislav Pavlovich

Dissertation: Dynamics of dental carries

Degree: Doc Med Sc1

Affiliation: Kaunas State Med Inst

Defense Date, Place: 13 Jan 54, Council of Inst of Experimental Medicine, Acad Sci Lithuanian

SSR

Certification Date: 16 Mar 57

Source: BMV0 13/57

CEPULYTE, V.

Stratigraphy of the Pleistocene deposits in Lithuanian SSR.

p. 53 (Mokslimiai Pranesimai) Vol. 4, 1957, Vilnius, Lithuania

SO: MONTHLY INDEX OF EAST EUROPEAN ACCESSIONS (MEAI) LC, VOL. 7, NO. 1, JAN. 1958

CEPULYTE, VALERIJA.

Lietuvos zemes pavirsius. Vilnius, Valistybine politines ir mokslines literaturos leidykla, 1957, 99. (4) p. (Pazinkime Lietuva) (The relief of Lithuania.)

SO: MONTHLY INDEX OF BAST EUROPEAN ACCESSIONS (REAI) LC. VOL. 7. NO. 1, JAN. 1958

CEPULYTE V.

CEPULYTE, V.

The geomorphological map of Lithuanian SSR.

p. 265 (Moksliniai Pranesimai) Vol. 4, 1957, Vilhius, Lithuania

SO: MONTHLY 1994 OF EAST EUROPEAN ACCESSIONS (EEAI) LC, VOL. 7, NO. 1, JAN. 1958

CEPULYTE, V.

GEOGRAPHY & GEOLOGY

MOUSLINIAI PRANESIMAI.

CEPULYTE, V. Geomorphological districts of Lithuania and their geologic development. p. 23.

Vol. 6, 1958.

Monthly List of East European Ascassion (EEAI) LC Vol. 8, No. 3
March 1959, Unallass.

## CHEPULITE, V. A. [Copulyte, V.]

Various conceptions of the term end moraine. Liet ak darbai B (EEAI 10:9) no.1:195-206 '61.

1. Institut geologii i geografii Akademii nauk Litovskoy SSR. (Moraines)

CRICYALIS, A.A. [Grigelis, A.], kand. geol.-min. nauk, oty. red.;
VONSAVICHYUS, V.P. [Vonsavicius, V.], red., GUDYALIS,
V.K. [Gudelis, V.], red.; DALINKEVICHYUS, I.A.
[Dalinkevicius, J.], red.; KAZAKOVA, V.A., red.;
KISNERYUS, Yu.L. [Kisnerius, J.], red.; CHEPULITE, V.A.
[Cepulyte, V.], red.; ASSOVSKIY, A.N., glav. red.

[Study of the geology of the U.S.S.R.] Geologicheskaia izuchemnost' SSSR. Glav. red. A.N.Assovskii i dr. Vil'nius, AN Litovskoi SSR. Vol.43.[Lithuanian S.S.R.; the period of 1800-1955] Litovskaia SSR; period 1800-1955. No.1. [Published works] Pechatnye raboty. 1962. 257 p. (MIRA 17:8)

1. Institut geologii i geografii AN Litovskoy SSR (for Grigyalis).

# CHEPULITE, V.A. [Gepulyte, V]

Basic bands of marginal formations in Lithuania and adjacent areas. Trudy AN Lit. SSR. Ser. B no.12169-187 62 (MIRA 17:8)

1. Institut geologii i geografii AN Litovskoy SSR.

CHEPULITE, V.A. [Cepulyte, V.]

Stratigraphic division of Quaternary sediments in the vicinity of Vilnius. Trudy AN Lit. SSR Ser. B no.3:53-86 '63.

(MIRA 18:3)

1. Institut geologii i geografii AN Litovskoy SSR.

CHEPULITE, V.A. [Cepulyte, V.A.]

Phase bands of the relief of the Recent Quaternary glaciation in the southeastern part of the Baltic Sea region. Trudy Kom. (MIRA 16:10)

1. Institut geologii i geografii AN Litovskoy SSR.

CHEPULITE, V.A. [Cepulyte, V.]

Stratigraphic division of Quaternary sediments in the surroundings of Kaunas. Trudy AN Lit. SSR. Ser.B no.1:77-103 '65. (MIRA 18:7)

1. Institut geologii i geografii AN Litovskoy SSR.

GARUNKSHTENE, S.S. [Garunkstiene, S.]; CRIGYALIS, A.A. [Grigelis, A.], kand. geo.-miner. nauk; VONSAVICHYUS, V.P. [Vonsavicius, V.], red.; GAYGALAS, A.I. [Gaigalas, A.], red.; DALINKEVICHYUS, I.A. [Dalinkevicius, J.], red.; KAZAKOVA, V.A., red.; KISNERYUS, Yu.L. [Kisnerius, J.], red.; CHEPULITE, V.A. [Cepulyte, V.]., red.

[Study of the geology of the U.S.S.R.] Geologicheskaia izuchennost' SSSR. Vil'nius, Mintis. Vol.43. No.1. 1964. 244 p. (MIRA 18:10)

CHEPUL'SKIY, V.G.

Device for fitting pump rotor wheels. Mashinostroenie no.4:33 J1-Ag 163. (MIRA 17:2)

OKARA, V.G.; CHEPUR, A.Ya.

Continuous line for the production of wide-flange I-beams.
Biul.tekh.-ekon.inform. no.12:3-5 '61. (MIRA 14:12)
(Rolling mills)

AKOP'YAN, A.S., red.; CHEPUR, B.D., red.

[Index of technical specifications for the Ukrainian S.S.R. as of January 1, 1961]Ukasatel' respublikanskikh tekhnicheskikh uslovii USSR; po sostoianiiu na 1 ianvaria 1961 goda. Izd. ofitsial'noe. Kiev, Otdel novoi tekhniki nauchno-issl. i proektnykh organisatsii. Podotdel standartov, 1961. 73 p. (MIRA 15:12)

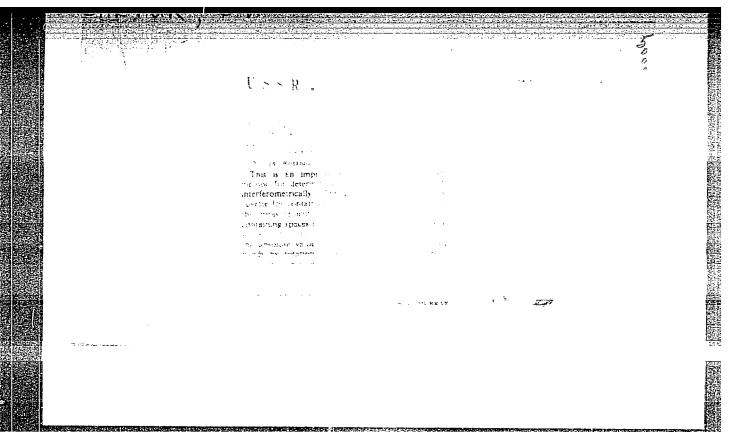
1. Ukraine. Gosudarstvennaya planovaya komissiya. (Ukraine-Standards, Engineering)

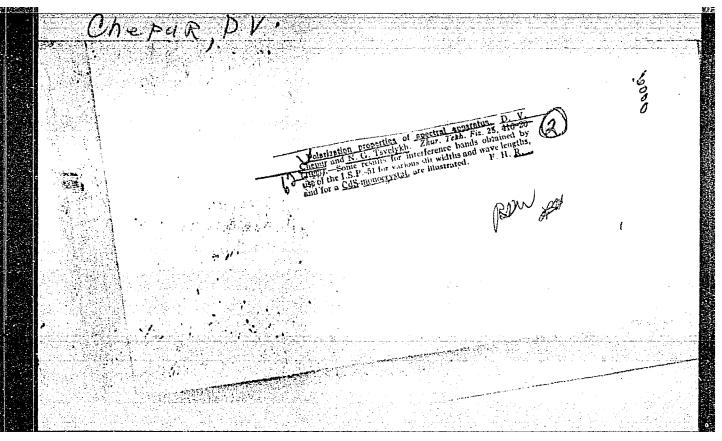
DANILEYKO, Vladimir Ivanovich[Danyleiko, V.I.]; CHEFUR, B.D., red.; LIBERMAN, T.R., tekhn. red.

[Life under space-flight conditions] Zhyttia v umovakh kosmichnoho pol'otu. Kyiv, Vyd-vo Akad. nauk URSR, 1961. 79 p. (MIRA 15:4)

(SPACE BIOLOGY)

(SPACE MEDICINE)





CHEPUR, D.V.
USSR/Physics - Conductivity of HgI<sub>2</sub> semiconductor

FD-3126

Card 1/2 Pub. 153 - 1/19

Author

: Chepur, D. V.; Petrusevich, V. A.

Title

Additional conductivity of HgI2 under the action of x-rays

Periodical

Zhur. tekh. fiz., 25, No 9 (September), 1955, 1523-1529

Abstract

The authors discuss the problem of developing and studying the photoelectric properties of effective semiconductor receivers of x-rays and the fact that certain semiconductors when irradiated by x-rays change their resistance by tens and hundreds of thousands of times, which therefore can serve as indicators of x-rays of even insignificant intensities. They note that S. V. Svechnikov (ibid., 22, 8, 1952) demonstrated that high sensitivity to x-rays is observed in CdS single-crystal, which is used now for certain practical purposes but is in limited use because of its considerable lifetime of photocurrent carriers. The authors discuss their experiments on HgI2, which shows extreme sensitivity to x-rays and considerably less inertia than CdS as indicated by oscillograms of photocurrent pulses (photocurrent in HgI2 falls to zero in time equal to 0.001-0.002 second). They study the voltampere characteristics, lux-ampere characteristics, the sign of the photocurrent carriers. They establish that the photo censitivity of HgI2 essentially depends upon spectral composition of x-ray radiation and

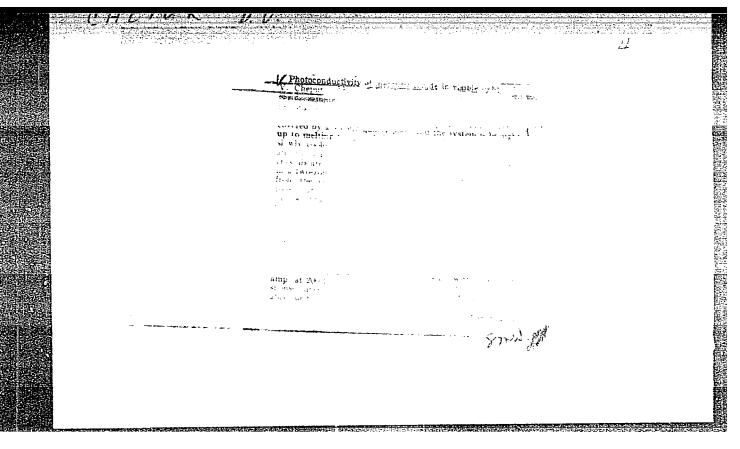
Card 2/2

FD-3126

increases with the brightness of the x-rays. They show that the photocurrent carriers are electrons and that the photo-resistance of HgI2 is of small inertia (time of relaxation equals about 0.001 second). Illumination by visible light can condition the increase in photocurrent by several times. The magnitude preparation of HgI2 specimens. The authors thank Professor V. Ye. Lashkarev, Active Member of Academy of Sciences of Ukrainian SSR, for his advice and interest. Three references: e.g. I. V. Poroykov, Rentgenometriya.

Institution: --

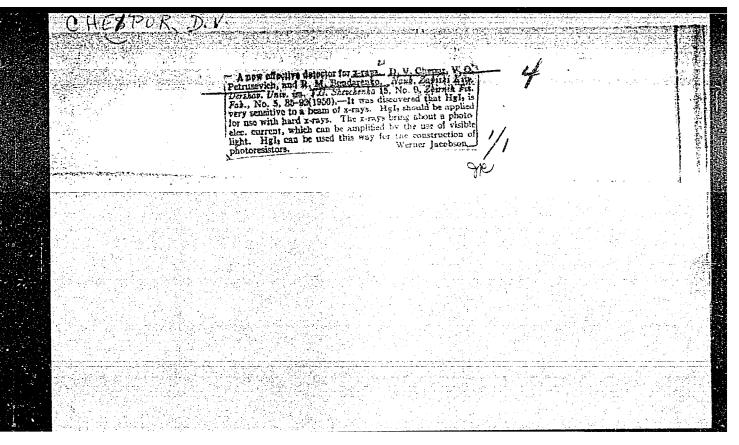
Submitted: March 28, 1955



Photoresistance of polycrystaline mercury iodide plated. Hauk povid. KDU no.1:30 '56. (MIRA 11:4)

(Mercury iodides--Optical properties)

(Photoconductivity)



Chapur, D. V.

Category : USSR/Electricity - Semiconductors

G-3

Abs Jour : Ref Zhur - Fizika, No 2, 1957, No 4214

: Chepur, D.V., Red'ka, O.A. Author

: Effect of Temperature on the Photoconductivity of Polycrystalline Mitle

Plates of HgI.

Orig Pub : Zh. tekhn. fiziki, 1956, 26, No 3, 553-559

Abstract : Polycrystalline layers of HgI, were prepared by evaporating the salt on the surface of a quartz plate and by further melting the obtained

layer between two quartz plates. The layers were then separated and electrodes deposited on them. The resistivity of the layers was approximately  $10^{13}$  ohm cm and dropped to  $10^8$  --  $10^6$  ohm cm upon illumination. The dark current and the photocurrent increased with increasing temperature. The transformation of the red modification of HgI2 into a yellow one at 1250 is accompanied by an increase in the dark resistivity and photoresistivity. The spectral characteristic has

one maximum in the ultraviolet region, and another at  $\frac{1}{100} = 590$  millimicrons. Increasing the temperature increases  $\frac{1}{100} = 590$  ents of photoconductivity were observed with  $\frac{1}{100} = 10^{-3}$  seconds and

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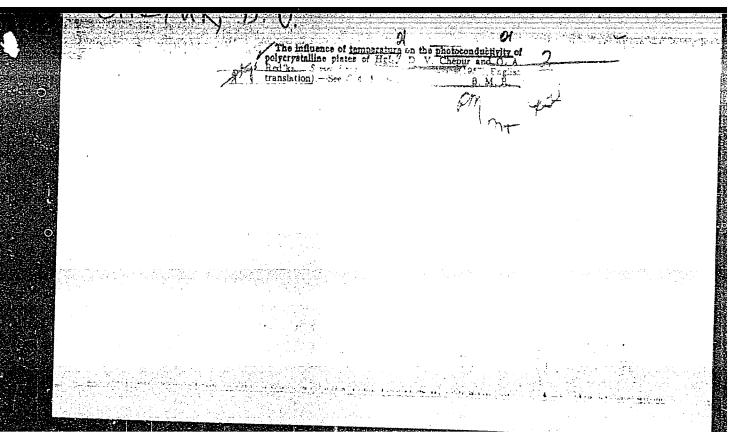
Category : USSR/Electricity - Semiconductors

G-3

Abs Jour : Ref Zhur - Fizika, No 2, 1957, No 4214

 $2 \times 10^{-3}$  seconds (at 20°). Illumination with white light causes to increase. The photosensitivity diminishes with the frequency at  $20^{\circ}$ . It was found that the mobility and concentration of the carriers are  $10 \text{ cm}^2/\text{v}$ . sec. and  $5 \times 10^{\circ} \text{ cm}^{-3}$  respectively. The quantum yield is 5%. Treating the layer with NH<sub>3</sub> with subsequent drying (50 -- 60°) and cooling to room temperature increases the photo sensitivity by 5 -- 10 times. A similar result is obtained by adding Te.

**Card** : 2/2



**AUTHOR** 

CHEPUR, D.V.

PA - 2587

TITLE

Photo-electrical and Optical Properties of HgJ2.

Fotoelektricheskiye i opticheskiye svoystva  $H_gJ_2$  - Russian

Radiotekhnika i Elektronika, 1957, Vol 2, Nr 3, pp 278-286 (U.S.S.R)

Reviewed 6/1957

Received 5/1957

ABSTRACT

PERIODICAL

Lecture delivered at the All Union Conference for Semiconductors in November 1955 at Leningrad. This paper deals with the following 2 problems: 1. Explanation of phenomena of electron processes due to absorbed electromagnetic radiation. 2. Relation between optic and photoelectric properties and the reasons for the particular characteristic features of individual samples. A procedure was developed for purposes of breeding monocrystals from a solution in acetone from a melt and by the evaporation of  ${\rm H_gJ_2}$  from the solid phase and in order to produce polycrystalline plates and films. The same results were obtained by investigations carried out both with monocrystals and plates. Rectangular and simusoidally modulatied light produced by ordinary mechanical modulators was used. The life of photocurrest carriers was determined according to the descending branch of photocurrent pulses. It depends on the wave length and attains its maximum at wavelenghts which corrsponds to the maximum of photosensitivity of the sample concerned in the visible domain of the spectrum. Additional illumination with constant intensity with white or monochromatic light at a wave length of 550 m increases the life of the photocurrent carriers. If temperature rises to 40-50° C the time characterizing most samples rema-

Card 1/2

Photo-electrical and Optical Properties of  $H_p J_2$ .

PA - 2587

ins unchange. In the case of a further increase of temperature life diminshes noticeable until photoactivity exists (the red modification turns yellow). Results show that  $H_gJ_2$  may be used for the production of efficacious photoresistances. (8 ill. and 6 citations from publications in Slav languages).

**ASSOCIATION** 

State Universities of Kiev and Uzhgorod

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Card 2/2

and optical properties of bi-indide of moreory." Kiev,

1958, 12 pp (Min of Higher Education UkSSR. Kiev State
Univ) 150 copies (KL, 50-58, 120)

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67202

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العيدات والمرواة

SOV/58-59-7-15782

Translation from: Referativnyy Zhurnal Fizika, 1959, Nr 7, p 161 (USSR)

**AUTHORS:** 

Chepur. D. M., Nasekovskiy, A.P.

TITLE:

Effect of Admixtures of Tellurium and Vapors of Certain Substances on the Photoconductivity of Polycrystalline Plates of Mercurous Iodide

PERIODICAL:

Dokl. i soobshch. Uzhgorodsk. un-t, 1958, Nr 2, pp 23 - 24

ABSTRACT:

The authors demonstrated experimentally that even minute amounts of Te (less than 0.001%) have a substantial effect on the magnitude and character of photoconductivity in polycrystalline plates of mercurous iodide. In the presence of admixtures of Te photoconductivity increases, inertness ordinarily decreases somewhat, and spectral characteristics spread appreciably in the direction of the longer wavelengths. As the concentration of Te is gradually increased, photoelectric sensitivity rises, while specific resistivity and inertness fall off. The enhanced sensitivity and reduced inertness point to an increase in the quantum

Card 1/2

67202

SOV/58-59-7-15782

Effect of Admixtures of Tellurium and Vapors of Certain Substances on the Photoconductivity of Polycrystalline Plates of Mercurous Iodide

yield of the photocurrent. A significant enhancement of the sensitivity of the investigated samples was also observed when they were placed in an atmosphere of vapors of ammonia, acetone, and ethyl and isoamyl alcohol.

N.V. Vasil chenko

Card 2/2

41654

\$/058/62/000/010/073/093

A061/A101

AUTHORS:

Dovgoshey, N. I., Chepur, D. V., Popovich, P. Yu.

TITLE:

Dependence of the degree of photosensitivity of mercuric iodide

samples on the frequency of an applied external field

PERIODICAL:

Referativnyy zhurnal, Fizika, no. 10, 1962, 45, abstract 10E349 ("Dokl. i soobshch. Uzhgorodsk. un-t. Ser. Fiz.-matem. n.", 1961,

no. 4, 52 - 53)

TEXT: It is shown that the sensitivity of mercuric iodide photoresistance cells fed by alternating voltage exceeds by several times their sensitivity in the case of constant voltage feeding. The explanation is that an alternating field does not permit the formation of a space charge that would lead to sample polarization.

[Abstracter's note: Complete translation]

Card 1/1

39111 S/058/62/000/006/132/136 A062/A101

9.4160

AUTHORS:

Kopinets, I. F., Chepur, D. V.

TITLE:

Effect of vapor adsorption of certain substances on the static characteristics of photoresistors made of mercury iodide

PERIODICAL:

Referativnyy zhurnal, Fizika, no. 6, 1962, 29, abstract 6-3-57y ("Dokl. i soobshch. Uzhgorodsk. in-t. Ser. fiz.-matem. n.", 1961,

no. 4, 54 - 55)

TEXT: The effect of vapor adsorption of certain substances on the photoconductivity of mono- and polycrystal specimens of mercury iodide,  $\operatorname{HgI}_2$ , was investigated. Vapors of ether and ethyl alcohol substantially increase the photosensitivity. Vapors of isoamyl alcohol have little effect. Vapors of benzol have practically no effect on the photosensitivity of  $\operatorname{HgI}_2$  specimens. The influence of the vapors is explained by the fact that adsorption considerably decreases the surface recombination rate of the photocarriers by increasing their life duration. This fact is confirmed by the investigations of the photoconductivity kinetics. Vapor adsorption leads also to an increase in the dark conductivity of the speci-

Card 1/2

Effect of vapor adsorption of ...

S/058/62/000/006/132/136 A062/A101

mens and a change in the shape of the spectral characteristics of the photoconductivity. There are 2 references.

V. L.

[Abstracter's note: Complete translation]

Card 2/2

L 10620-65 ENT(1)/ENG(k)/EPE/EEG(b)-2 P2-6/Ps-L AEDC(b)/LJP(e)/ASD(a)-5/SSD/ AFWL/ESD(t)/RAFM(t) AT ACCESSION NR: AT4048105 S/3114/61/000/004/0058/0059 AUTHOR: Semak, D. G., Chepur, D. V. TITLE: Some thermoelectric properties of cuprous lodide B SOURCE: Uzhgorod. Universitet. Doklady\* i soobshcheniya. Seriya fiziko-mathematicheskikh nauk, no. 4, 1981, 58-59 TOPIC TAGS: cuprous iodide, thermoelectric property, resistor, semiconductor, conductivity, thermocouple ABSTRACT: This note presents some data on the thermoelectric properties of pressed semicrystalline "tablets" of cuprous lodide having a resistivity at room temperature of 2 x 103 ohm/cm. It was found that for the range 20-80C, a 1C increase in temperature lowered the resistance by 20 chms. The thermoelectromotive force of cuprous iodide amounts to  $3-5 \times 10^{-4}$  volts/degree. It was found that when the cool electrode is kept at room temperature, the thermoelectromotive force depends in a linear fashion on the temperature gradient between the electrodes, varying from 4.6 to 27.6 mv as the temperature gradient increased from 15 to 75C. Cuprous iodide may therefore be useful in the measurement of temperature gradients. Orig. art. has: 1 table. Card 1/2

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	1. 6678-65 EWP(1)/EPA(a)-2/EWP(k)/EWP(a)/EPF(a)/EMP(k)-2/EVP/A)/EPF(a)/EMP(k)-2/EVP/A)/	120.572 11 T
	1. 6678-65 EWP(1)/EPA(a)-2/EWD(k)/EWP(a)/EPF(a)/EDE(k)-2/EWP/T/EEG(b)-2/EWP(b)/EWP(1)/EWP(1)/ Pd-1/Pa-6/Pa-6/Pa-1/Pa-6/Pa-6/Pa-1/Pa-6/Pa-6/Pa-6/Pa-6/Pa-6/Pa-6/Pa-6/Pa-6	
	AUTHOR: Chepur, D. V., Dovgoshey, N. I., Kopinets, I. F.	
1:	TITLE: The stability of operation and possibility of practical application of photoresistors of mercurous todide	
	SOURCE: Uzhgorod. Universitet. Doklady* i soobshcheniya. Seriya fiziko-mathemati- cheskikh nauk, no. 4, 1981, 81-82	
	TOPIC TAGS: photoresistor, photoconductivity, electrode, roentgenography, mercurous lodide	
ない かんしゅう	ABSTRACT: The authors note briefly that photoresistors of mercurous iodide have a period of "aging", which lasts for a few days, and during which the sensitivity usually decreases by 30-40% (in rare cases by up to 60-70%). After this period of aging, the changes cease and the operation of the photoresistor is quite stable. Experiments lasting 8-12 months have shown that many of the photoconductivity characteristics do not vary with use.	
	However, the electrodes do seem to play an active role in guaranteeing the stability of operation of the photoresistor; coating the electrodes with a thin film of polystyrens or	
4	Card 1/2	

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ACCESSION NR: AT4048108

VF-2 adhesive is recommended. The stability of the photoconductivity characteristics indicates that photoresistors of mercurous icdide may be useful in light meters, in portable dosimeters for ionizing radiation, and to replace resistors of cadmium sulfate.

4 2

ASSOCIATION: Unhgorodiskiy gosuniversitet (Unhgorod State University)

SO REP BOY 1991

8/058/62/000/006/033/136 A061/A101

AUTHORS:

Turyanitsa, I. D., Chepur, D. V., Koperles, B. M.

TITLE:

A photoelectric study of absorption, reflection, and dispersion of

mercurous iodide specimens

PERIODICAL: Referativnyy zhurnal, Fizika, no. 6, 1962, 33, abstract 6V220

("Dokl. i soobshch. Uzhgorodsk. un-t. Ser. Fiz.-matem. n.", 1961,

no. 4, 60)

The curves of absorption, reflection, and dispersion of mercurous TEXT: iodide single crystals and polycrystalline films were measured at room temperature. The principal absorption maximum was situated in the ultraviolet, and the additional one (580 m $\mu$ ) was due to stoichiometric iodine excess. The reflection factor was  $\approx 10\%$  and > 20% in the red and violet spectrum regions, respectively.

[Abstracter's note: Complete translation]

Card 1/1

Accession nr: Ar3005166	5/0058/63/000/006/2081/2081
SOURCE: RZh. Fizika, Abs. 6 E5	45
AUTHORS: Kopinets, L. F.; Chepur	
TITLE: Effect of adsorption of a conductivity and dark conductivity	molecules of some substances on the photo- ty of mercury-iodide specimens
ITED SOURCE: Dokl. 1 soobsheh. No. 5, 1962, 58-59	<u>Uzhgorodsk. un-t.</u> Ser. Fizmatem. i istor. n.,
TOPIC TAGS: Mercury iodide, phonolecules, ethyl alcohol, methyl	toconductivity, dark current, adsorption of alcohol, benzene, acetone, water, air
of adsorption of molecules of dis dinetics of photoconductivity of from the gas phase. The adsorpti	ed of experimental investigations of the influence of mercury lodide specimens obtained by sublimation in of molecules of ethyl and methyl alcohol and 2-3 orders of magnitude) the dark conductivity,

ACCESSION NR: AR3005166		0
able influence on the af- the case of adsorption of physical adsorption, but tional energy levels, on	cules of benzene, water, and air does orementioned parameters. It follows f vapor of alcohol and acetone there also chemisorption, which causes the which dissociation of excitons take free carriers, i. e., increases the	therefore that in occurs not only occurrence of addi- place. This increases
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L 8380-65 EWT(1)/EWG(k)/EEC(t) Pz-6 IJP(c)/SSD/AS(mp)-2/AFWL/ESD(gs)/ESD(t) PAEM(t) AT ACCESSION NR: AR4044021 5/0058/63/000/011/A024/A024 SOURCE: Ref. zh. Fizika, Abs. 11A244 AUTHOR: Goncharenko, Ye. T.; Dovgoshey, N. I.; Chepur, D. V. TITLE: Certain specific properties of photoresistors during work with variable fields of differing frequencies CITED SOURCE: Dokl. i soobshch. Uzhgorodsk. un-t. Ser. fiz.-matem. i istor. n., TOPIC TAGS: photoresistor, photoconductivity, photosensitivity TRANSLATION: Investigates the dependence of the value of photoconductivity of factory photoresistors FS-K1, FS-DO, and FS-DI on the frequency of the applied external field. It is shown that the shape of the volt-ampere and the luxampere characteristics of all types of photoresistors when working with variable fields remains the same as in the case of an equivalent constant field. In the investigated range of frequencies (50-20,000 cps) the magnitude of the photosensitivity is not a function of the frequency of the applied external field, and is Card 1/2

	L 8380-65 ACCESSION NR: AR4044021
	2-3 times greater than the value of the photosensitivity corresponding to a constant field.
	SUB CODE: EC, EM ENCL: 00
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	L 2/2

EWA(h)/EWT(1)/EWP(q)/EWT(m)/BDS/EEC(b)-2 AFFTC/ASD/ESD-3/IJP(C) ACCESSION NR: AR3005167 RDM/WW/JD 8/0058/63/000/006/2095/2095 SOURCE: RZh. Fizika, Abs. 6 E637 AUTHORS: Dovgoshey, N. I.; Chepur, D. V.; Skunts, V. A. TITLE: Added conductivity of polycrystalline specimens of cadmium selenide induced by x-rays CITED SOURCE: Dokl. i soobshch. Uzhgorodsk. un-t. Ser. Fiz.-matem. i istor. n., no. 5, 1962, 61-64 TOPIC TAGS: Cadmium selenide, additional conductivity, photoconductivity, x-ray, dosimetry TRANSLATION: A detailed investigation was made of the additional conductivity of polycrystalline specimens of CdSe, induced by x-rays. The volt-ampere characteristics of photoresistors FS-DO and DS-DI in darkness and under irradiation are nonlinear and are described by a power-law dependence with exponent equal to 1.2--1.5 for FS-DQ and 1.05--1.25 for FS-DI. A decrease in the hardness of the x-rays improves the linearity of the volt-ampere characteristics. The value of the additional current depends little on the hardness of the x-rays. The photo-

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resistors FS-DO and FS-D1 used as transducers for do	were found to simeters for	o be high soft x-r	ly sensiti ays. F. N	ve to x-rays	and can be
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CHEPUR, D.V.; DOVGOSHEY, N.I.; TIMOSHIN, V.P.

New variant of an apparatus for studying the rectifying properties of low-power semiconductor diodes. Dokl. i soob. UzhGU. Ser. fiz.-mat. i ist. nauk no.5:64-65 '62.

(MIRA 17:9)

L 13047-63 EWP(q)/EWT(m)/BDS AFFTC/ASD RDW/JD
ACCESSION NR: AT3002997 S/2927/62/000/000/0141/0144 5 7

AUTHOR: Dovgoshey, N. I.; Chepur, D. V.

TITLE: Properties of film detectors based on cadmium selenide [Report of the All-Union Conference on Semiconductor Devices held in Tashkent from 2 to 7 October 1961]

SOURCE: Elektronno-dy\*rochny\*ye perekhody\* v poluprovodnikakh. Tashkent, Izd-vo AN UzSSR, 1962, 141-144

TOPIC TAGS: cadmium selenide film detector

ABSTRACT: Two objects are described in the article: (1) a cadmium-selenide film detector developed by the authors and (2) a special electronic outfit for testing the detector. Copper, brass, aluminum, and nickel-plated iron (roved the best) PLATES WERE VACUUM"SPRAYED WITH CdSe, formed, and tested. Depending on the thickness of CdSe film, the best durable-formation voltage was found to be 10 to 70 v. Variation of characteristics with the time of continuous operation (up to 30 min) was observed: rectification factor changed from 200 to 1,000 in some cases. A special electronic tester was developed for measuring current-voltage and dynamic characteristics and for forming and welding the rectifiers. The tester and its operation procedures are described in detail. Orig. art. has: 1 figure.

DOVGOSHEY, N.I.; CHEPUR, D.V.

Unit for investigating rectifying properties of low-power crystal diodes. Izv.vys.ucheb.zav.; prib. 6 no.6:137-139 '63. (MIRA 17:3)

1. Uzhgorodskiy universitet. Rekomendovana kafedroy obshchey fiziki.

L 3hh6-66 EWT(m)/ETC/EWG(m)/EWP(t)/EWP(b) IJP(c) RDW/JD/GS ACCESSION NR: AT5020487 UR/0000/64/000/000/0405/0413 AUTHORS: Chepur, D. V.; Dovgashey, N. I.; Goncharenko, Ye. T. 53 B+1 TITLE: Concerning contacts and certain properties of mercuric iodide photo-SOURCE: Mezhvuzovskaya nauchno-tekhnicheskaya konferentsiya po fizike poluprovodnikov (poverkhnostnyve i kontaktnyve yavleniya). Tomsk. 1962. Poverkhnostnyye i kontaktnyye yavleniya v poluprovodnikakh (Surface and contact phenomena in semiconductors). Tomsk, Izd-vo Tomskogo univ., 1964, 405-413 TOPIC TAGS: mercuric iodide, photoresistor, photosensitivity / SG 2M electrom-ture) mono- and polycrystalline specimens of mercuric iodide to determine the effect of contacts and to study the aging of photoresistors and some of their properties in variable electric fields. The specimens were prepared and the measurements were made by the procedures and apparatus described by D. V. Chepur (ZhTF, 25, 14, 1955). The field distributions along the specimens were plotted by the movable-probe method with platinum-wire electrodes with a diameter of Cord 1/3

#### L 3446-66

#### ACCESSION NR: AT5020487

0.3 mm. An SG-2M electrometer was used to measure voltage, and an IZA-2 comparator was used to measure the distance between the probes. A ZG-10 audio oscillator and a 1321-V vacuum-tube voltmeter were also used. Aquadag and platinum were found to be the best contact materials for HgI, photoresistors; their use provided

linear volt-ampere characteristics under illumination and in the dark. A typical aging curve for one of the specimens is shown in Fig. 1 on the Enclosure. The use of variable instead of constant electric fields led to an increase in photosensitivity by a factor of 1.5-2, and also to an improvement in stability. Orig. art. has: 6 graphs and 1 diagram.

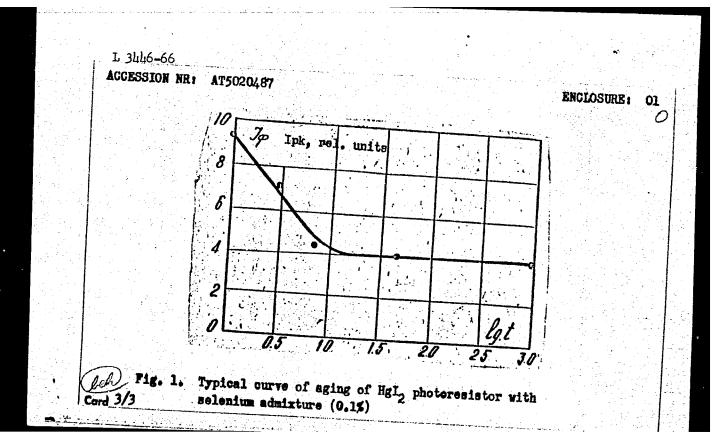
ASSOCIATION: none 

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ENGL: 01 OTHER: 001

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L 3447-66 EWT(m)/EPF(c)/T/EWP(t)/EWP(b) IJP(c) JD/GS
ACCESSION NR: AT5020488 UR/0000/64/000/000/0414/0421
59

AUTHORS: Kopinets, I. F.; Kuznetsova, S. T.; Chepur, D. V.

TITLE: The effect of adsorption of the vapors of certain substances on the photoelectric properties of mercuric iodide

SOURCE: Mezhvuzovskaya nauchno-tekhnicheskaya konferentsiya po fizike poluprovodnikov (poverkhnostnyye i kontaktnyye yavleniya). Tomsk, 1962. Poverkhnostnyye i kontaktnyye yavleniya v poluprovodnikakh (Surface and contact phenomena in semiconductors). Tomsk, Izd-vo Tomskogo univ., 1964, hlh-421

TOPIC TAGS: adsorption, mercuric iodide, photoelectric property, carbon dioxide, methane, hydrogen peroxide, ammonia, benzene, methanol, ethanol, ether, acetone, cryostat, dark conductivity, semiconductor/ M17/9 galvanometer

ABSTRACT: Experiments were performed on the effect of adsorption of carbon dioxide, methane, water, hydrogen peroxide, ammonia, benzene, methanol, ethanol, ether, and acetone on the dark conductivity, static characteristics, and kinetics of the photoconductivity of single crystals and polycrystalline ingots of red mercuric iodide. The work was performed to obtain information on the effect of surface phenomena on the above characteristics of red Hgl2. Specimens with thick-

L 3447-66

ACCESSION NR: AT5020488

nesses of from 1-2 to 0.01 mm -- prepared by sublimation from the gaseous phase -- were studied in a cryostat, and the conductivity was measured with an M17/9 galvanometer; It was found that adsorption of vapors of carbon dioxide, methane, water, benzene, and ether have little effect on the dark conductivity, effective carrier lifetime, and quantum yield of HgI2, while vapors of methanol, ethanol, acetone, hydrogen peroxide, and ammonia increase the photo- and dark conductivity, effective carrier lifetime, and quantum yield. This increase was interpreted on the basis of F. F. Vol'kenshteyn's theory of chemosorption (Elektronnaya teoriya kataliza na poluprovodnikakh, Fizmatgiz, 1960) by free electrons and holes, as well as by excitons, with the latter dominating. Orig. art. has: 4 graphs, 1 figure, and 3 formulas.

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ASSOCIATION: 133). Ushgorodekly gosuniversitet (Ushgorod State University)

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OTHER: 003

CIA-RDP86-00513R000308330006-8" APPROVED FOR RELEASE: 06/12/2000

ACC NR: AR6033781 SOURCE CODE: UR/0058/66/000/007/D089/D089

AUTHOR: Dovgoshey, N. I.; Chepur, D. V.; Nikolyuk, R. G.

TITLE: Some optical properties of thin  $CdS_x$ .  $CdSe_{1-x}$  films

SOURCE: Ref. zh. Fizika, Abs. 7D717

REF SOURCE: Sb. tezisy dokl. k XIX Nauchn. konferentsii. Uzhgorodsk. un-t, 1965. Ser. fiz. Uzhgorod, 1965, 34-39

TOPIC TAGS: absorption spectrum, cadmium selenide film, reflection spectrum, cadmium sulfide film, metal film, reflection coefficient, mirror reflection, diffuse reflection, reflection, opties, optical property, solid solution, substitutional solid-solution

ABSTRACT: A study was made of reflection and absorption spectra in the 400—700-m  $\mu$  range, of thin CdS<sub>0.25</sub>. CdSe<sub>0.75</sub> films, 0.4—0.8- $\mu$  thick (the indices indicating the weights of the initial components), obtained on cold and heated (up to 300C) backings. All the films showed an inverse dependence of the effective coefficient of reflection R on the thickness of the film at all temperatures. This is explained by the fact that R is determined both by the mirror and diffuse reflection.

Card 1/2

ACC NR: AR6033781

A lower R value in films deposited on cold backings is explained by the smoothing out of the microrelief surface when a layer is deposited on a heated backing. The absorption spectrum of films deposited on hot backings is shifted toward the long-wave region, which is due to the somewhat larger amount of CdSe in the films than in those formed on cold backings. The conclusion is reached that  $CdS_x$ .  $CdSe_{1-x}$  films represent a substitutional solid solution. S. Bureyko. [Translation of abstract]

SUB CODE: 20/

Card 2/2

L 0805h-67 EWT(1)/EWT(m)/ENP(t)/ETI IJP(c) JD/AT

ACC NRI AR6031889 SOURCE CODE: UR/0058/66/000/006/E095/E095

AUTHOR: Semak, D. G.; Chepur, D. V.; Goyer, D. B.

TITLE: Photostimulation and photoelectret state of mercury iodide single crystals

SOURCE: Ref. zh. Fizika, Abs. 6E748

REF SOURCE: Sb. Tezisy dokl. k XIX Nauchn. konferentsii. Uzhgorodsk. un-t, 1965. Ser. fiz. Uzhgorod, 1965, 47-52

TOPIC TAGS: electret, single crystal, mercury iodide, electrometer, photostimulation

ABSTRACT: It has been found that HgJ2 single crystals possess electret properties at low temperatures. Investigation was carried out at 77K on single crystals of the red modification of HgJ2, grown from a solution in an acetone. To detect the electret state, a standard procedure was used for measuring the polarization value according to the initial deflection of the electrometer upon depolarization by light. It is shown that the photoelectret properties of HgJ2 are related to adhesion in this compound. F. Nad. [Translation of abstract] SUB CODE: 20/

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ACC No. ARGO31894 SOURCE CODE: UR/0058/66/000/000/E100/E100/E100/E100/E100/E10	
TITLE: Absorption and photoconductivity of mercury iodide  SOURCE: Ref. zh. Fizika, Abs. 6E790	
REF SOURCE: Sb. tezisy dokl. k XIX Nauchn. konfernetsii: Uzhgorodsk. un-t, 1965. Ser. fiz. Uzhgorod, 1965, 65-68	
TOPIC TAGS: mercury iodide, mercury iodide absorption, mercury iodide photoconductivity	.
ABSTRACT: Optical absorption and photoconductivity of HgJ single crystals was investigated. Prolonged exposure of HgJ crystals to light results in a chemical transformation of HgJ to HgJ2 with the separation of Hg. Consequently, the HgJ single crystals were grown in the dark. HgJ was found to be transparent over a wide spectral region. A noticeable absorption starts with $1 \approx 5500 \ \lambda$ , reaches its maximum at $\lambda \approx 5000 \ \lambda$ and then decreases again. From one specimen to another, the absorption coefficient in the maximum fluctuates within	
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700—1000 cm <sup>-1</sup> .	Therefore, there is re	eason to cons	sider tha	t the max	imum at	Ses
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LWI(1)/EWT(m)/EWP(t)/ETI IJP(c) JD/GG

ACC NR: AR6031892

SOURCE CODE: UR/0058/66/000/006/E097/E097

AUTHOR: Magda, I. N.; Semak, D. G.; Chepur, D. V.

46

TITLE: The photodielectric effect of mercury iodide

77

SOURCE: Ref. zh. Fizika, Abs. 6E765

REF SOURCE: Sb. Tezisy dokl. k XIX Nauchn. konferentsii. <u>Uzhgorodsk. un-t</u>, 1965, Ser. fiz. Uzhgorod, 1965, 72

TOPIC TAGS: photodielectric effect, dielectric constant, space charge, grain boundary, mercury iodide

ABSTRACT: The photodielectric effect has been detected in  $\operatorname{HgJ}_2$ . When  $\operatorname{HgJ}_2$  placed as a dielectric between capacitor plates was illuminated, an increase in dielectric constant is was observed. At low temperature this change is maintained with time, and with decrease in temperature value is itself decreases only slightly. It is supposed that in  $\operatorname{HgJ}_2$  the photodielectric conductivity is linked to the formation of the space charge on the grain boundaries owing to the electron localization in the traps.

SUB CODE: 20, 09/

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L 08334-67 EWT(m)/EWP(t)/ETI IJP(c) JD/JG

ACC NR: AR6017156 SOURCE CODE: UR/0275/66/000/001/B032/B032

AUTHOR: Chepur, D. V.; Dovgashey, N. I.; Goncharenko, Ye. T.

TITLE: Concerning contacts and certain photoresistive properties of mercury bilodide

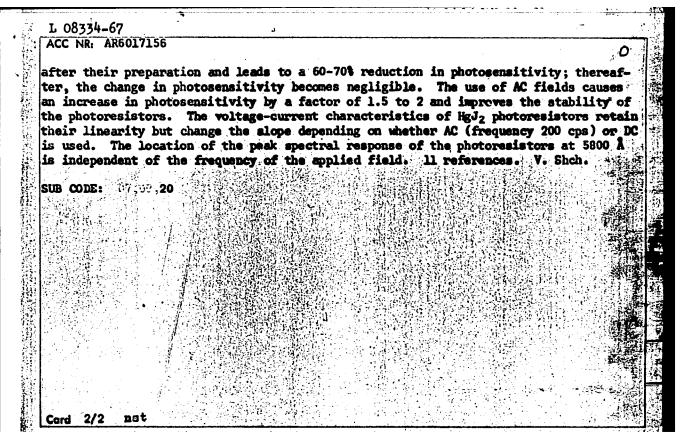
SOURCE: Ref. zh. Elektronika i yeye primeneniye, Abs. 1B251

REF SOURCE: Sb. Poverkhnostn. i kontaktn. yavleniya v poluprovodnikakh. Tomsk. Tomskiy un-t, 1964, 405-413

TOPIC TAGS: photoresistance, photoresistor, photoconductance, photoconductor, mercury compound

TRANSLATION: The effect of the contacts, the aging process and certain other properties of mercury biodide photoresistors are investigated. The photoresistors were prepared from pure mono- and polycrystalline samples and from samples containing selenium impurities. The experimental investigations showed that it is most expedient to use aquadag or Pt which are quite stable over a wide temperature range. Curves are presented showing the electrical field distribution in the samples immediately after the deposition of the aquadag electrodes and after thorough drying; these curves prove that the photoresistors with freshly deposited contact have only a very low transfer resistance whereas after the drying of the electrodes the transfer contact resistance can be measured. The HgJ<sub>2</sub> photoresistor aging process occurs during the first 10-20 hrs

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L 09382-67 EWT (m)/EWP(t)/EII IJP(c) JD

ACC NR: AR6033773 SOURCE CODE: UR/0058/66/000/007/A050/A050

AUTHOR: Dovgoshey, N. I.; Chepur, D. V.; Gryadil', I. A.; Nikolyuk, R. G.;

Yatskovich, I. I.

TITLE: Microrelief and structure of thin films of cadmium sulfide and cadmium selenide

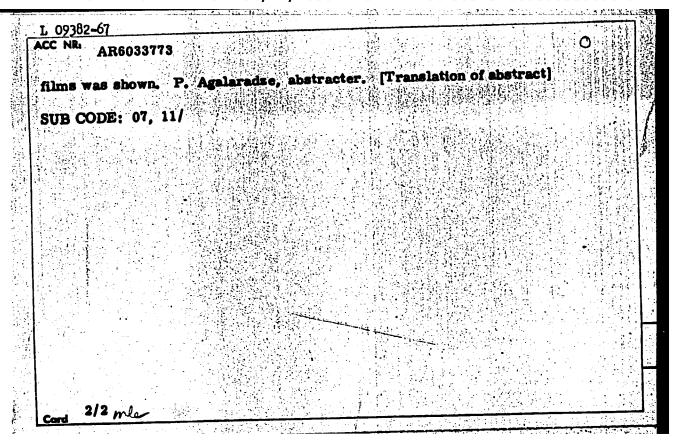
SOURCE: Ref. zh. Fizika, Abs. 7A426

REF SOURCE: Sb. Tezisy dokl. k XIX Nauchn. konferentsii. Uzhgorodsk. un-t, 1965. Ser. fiz. Uzhgorod, 1965, 25-29

TOPIC TAGS: cadmium selenide, cadmium sulfide, thermal spraying, cadmium film

ABSTRACT:  $CdS_X$  and  $CdSe_{1-X}$  films were obtained by thermal spraying under vacuum (10<sup>-4</sup> mm) on cold glass backings and glass backings heated to 120, 200, 250, and 300°C. Cadmium sulfide and cadmium selenide powders mixed in a specific ratio served as the source material. The films consisted of small crystals of fine crystals of a substitutional solid solution of  $CdS_X \cdot CdSe_{1-X}$ . It was found that the films have a hexagonal grain orientation with an axis [0001] perpendicular to the backing. The non-correspondence of the source material composition and the Cord 1/2

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1.09381-67 EWI(m)/EWP(t)/EII IJP(c) JD

ACC NRI AR6033772 S

SOURCE CODE: UR/0058/66/000/007/A050/A050

AUTHOR: Dovgoshey, N. I.; Chepur, D. V.; Gryadil', I. A.

22

TITLE: Effect of the temperature of the glass backing on structure of thin films of cadmium selenide and sulfide

SOURCE: Ref. zh. Fizika, Abs. 7A425

REF SOURCE: Sb. Tesisy dokl. k XIX Nauchn, konferentsii. Ushgorodsk. un-t, 1965. Ser. fiz. Uzhgorod, 1965, 30-34

TOPIC TAGS: cadmium selenide, cadmium sulfide, cadmium film, film orientation

ABSTRACT: CdSe and CdS films were obtained by thermal spraying of the respective compounds on cold glass backings and on glass backings heated to 60 to 400C. All CdS films were shown to be grain-oriented. With  $t_n$  = 60C, the fine crystals of the films are of a hexagonal modification with an axis [0001], perpendicular to the backing. With  $t_n$  = 100—200C, a cubic CdS modification appears with an axis [111] perpendicular to the backing. The CdSe films are likewise grain-oriented. When  $t_n$  = 60—100C, the hexagon axis [0001] is perpendicular to the backing plane. The

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CdSe cubic phase a lation of abstract]	ppears when $t_n > 15$	oC. P. Agala	radse, abstracte	r. [Trans-
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ACC NR. AR6031890 SOURCE CODE: UR/0058/66/000/006/E095/E095

AUTHOR: Turyanitsa, I. D.; Chepur, D. V.; Golovey, M. I.; Solyanik, E. Yu.; Gurzan, M. I.

TITLE: Specific characteristics of antimony iodide photoconductivity and absorption

SOURCE: Ref. zh. Fizika, Abs. 6E749

REF SOURCE: Sb. Tezisy dokl. k XIX Nauchn. konferentsii. Uzhgorodsk. un-t, 1965, Ser. fiz. Uzhgorod, 1965, 58-65

TOPIC TAGS: iodide, antimony, antimony iodide, x ray structural analysis, dark current, main absorption band

ABSTRACT: The photoelectrical and optical properties of SbJ3 specimens obtained by crystallization from the vapor phase in air or vacuum were investigated. X-ray structural analysis showed that the specimens obtained were single-crystals and that those obtained under vacuum were more prefect than those grown in air. The dark current depends exponentially on the temperature and has an activation energy of 0.9 ev. The width of the forbidden band determined on the basis of the longwave boundary of the main absorption band corresponds to 2.14 ev. It follows, therefore,

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